

深圳市巴丁微电子有限公司

SHEN ZHEN BARDEEN MICROELECTRONICS CO., LTD

Features

- Single-Supply Operation from +2.1V ~ +5.5V
- Rail-to-Rail Input / Output
- Gain-Bandwidth Product: 1MHz (Typ)
- Low Input Bias Current: 1pA (Typ)
- Low Offset Voltage: 3.5mV (Max)
- Quiescent Current: 40µA per Amplifier (Typ)
- Operating Temperature: -40°C ~ +125°C

General Description

- Embedded RF Anti-EMI Filter
- Small Package:
- BDM321 Available in SOT23-5 Package

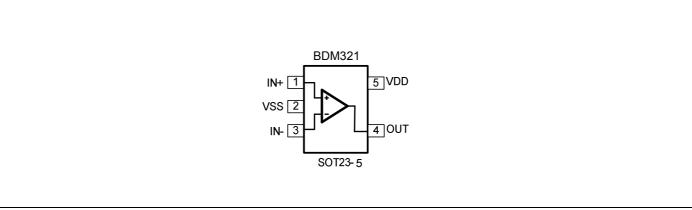
The BDM321 have a high gain-bandwidth product of 1MHz, a slew rate of 0.6V/µs, and a quiescent current of 40uA/amplifier at 5V.The BDM321 is designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common mode voltage range includes ground, and the maximum input offset voltage is 3.5mV for BDM321. They are specified over the extended industrial temperature range (-40 $^{\circ}$ C to +125 $^{\circ}$ C). The operating range is from 2.1V to 5.5V. The BDM321 single is available in Green SOT-23-5 package.

Applications

- ASIC Input or Output Amplifier
- Sensor Interface
- Medical Communication
- Smoke Detectors

Pin Configuration

- Audio Output
- Piezoelectric Transducer Amplifier
- Medical Instrumentation
- Portable Systems







Absolute Maximum Ratings

Condition	Min	Max			
Power Supply Voltage (V _{DD} to Vss)	-0.5V	+7.5V			
Analog Input Voltage (IN+ or IN-)	Vss-0.5V	V _{DD} +0.5V			
PDB Input Voltage	Vss-0.5V	+7V			
Operating Temperature Range	-40°C	+125°C			
Junction Temperature	+160	+160°C			
Storage Temperature Range	-55°C	+150°C			
Lead Temperature (soldering, 10sec)	+260	+260°C			
Package Thermal Resistance (T _A =+25℃)					
SOP-8, θ _{JA}	125°0	125°C/W			
MSOP-8, θ _{JA}	216°	216°C/W			
SOT23-5, θ _{JA}	190°0	190°C/W			
SC70-5, θ _{JA}	333°0	333°C/W			
ESD Susceptibility					
НВМ	6K	6KV			
MM	300	300V			

Note: Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Package/Ordering Information

MODEL	CHANNEL	ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION	MARKING INFORMATION
BMD321	Single	BDM321-TR	SOT23-5	Tape and Reel,3000	321



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Electrical Characteristics

(At Vs = +5V, RL = $100k\Omega$ connected to Vs/2, and Vout = Vs/2, unless otherwise noted.)

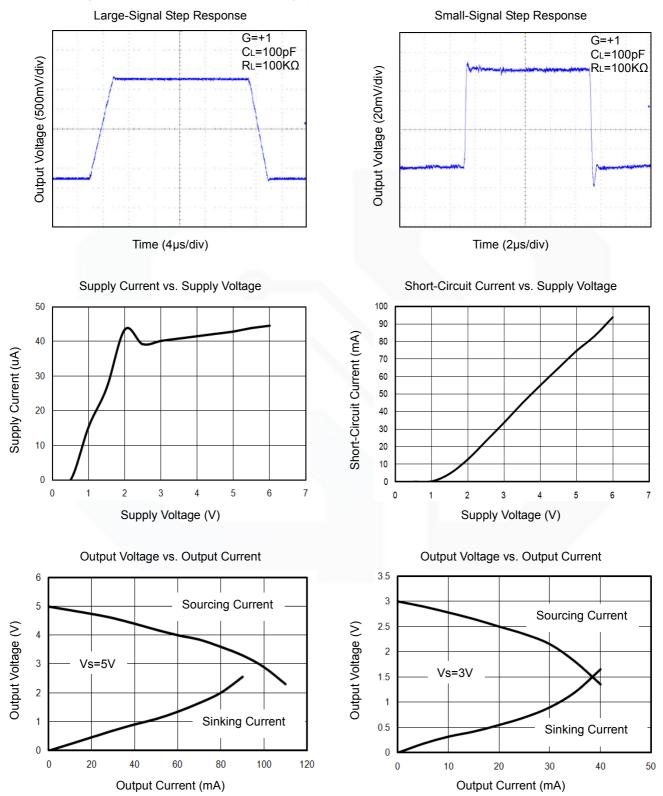
	SYMBOL	CONDITIONS	BDM321				
PARAMETER			ТҮР	MIN/MAX OVER TEMPERATURE			
			+25℃	+25℃	-40℃ to +85℃	UNITS	MIN/MAX
INPUT CHARACTERISTICS		·					
Input Offset Voltage	Vos	$V_{CM} = V_S/2$	0.4	3.5	5.6	mV	MAX
Input Bias Current	IB		1			pА	TYP
Input Offset Current	los		1			pА	TYP
Common-Mode Voltage Range	V _{CM}	V _S = 5.5V	-0.1 to +5.6			V	TYP
Common-Mode Rejection Ratio	CMRR	$V_{\rm S}$ = 5.5V, $V_{\rm CM}$ = -0.1V to 4V	70	62	62	dB	MIN
		$V_{\rm S}$ = 5.5V, $V_{\rm CM}$ = -0.1V to 5.6V	68	56	55		
Open-Loop Voltage Gain		$R_{L} = 5k\Omega, V_{O} = +0.1V \text{ to } +4.9V$	80	70	70	dB	- MIN
	A _{OL}	R_L = 10k Ω , V_O = +0.1V to +4.9V	100	94	85		
Input Offset Voltage Drift	$\Delta V_{OS} / \Delta_T$		2.7			µV/°C	TYP
OUTPUT CHARACTERISTICS							
Output Voltage Swing from Rail	V _{он}	R _L = 100kΩ	4.997	4.990	4.980	V	MIN
	V _{OL}	R _L = 100kΩ	3	10	20	mV	MAX
	V _{он}	R _L = 10kΩ	4.992	4.970	4.960	V	MIN
	V _{OL}	R _L = 10kΩ	8	30	40	mV	MAX
Output Current	ISOURCE	$R_L = 10\Omega$ to $V_S/2$	84	60	45	- mA	MIN
	I _{SINK}		75	60	45		
POWER SUPPLY							
Operating Voltage Range				2.1	2.5	V	MIN
				5.5	5.5	V	MAX
Power Supply Rejection Ratio	PSRR	$V_{\rm S}$ = +2.5V to +5.5V, $V_{\rm CM}$ = +0.5V	82	60	58	dB	MIN
Quiescent Current / Amplifier	Ιq		40			μA	TYP
DYNAMIC PERFORMANCE (CL	. = 100pF)						
Gain-Bandwidth Product	GBP		1			MHz	TYP
Slew Rate	SR	G = +1, 2V Output Step	0.6			V/µs	TYP
Settling Time to 0.1%	ts	G = +1, 2V Output Step	5			μs	TYP
Overload Recovery Time		V _{IN} ⋅Gain = V _S	2.6			μs	TYP
NOISE PERFORMANCE							
Voltage Noise Density		f = 1kHz	27			nV/\sqrt{Hz}	TYP
	en	f = 10kHz	20			nV / \sqrt{Hz}	TYP



BDM321

Typical Performance characteristics



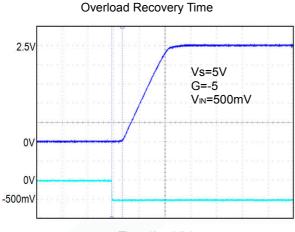




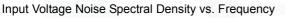
BDM321

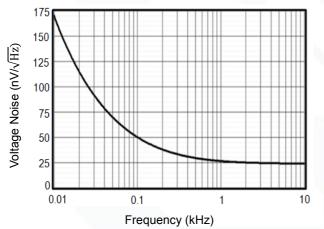
Typical Performance characteristics

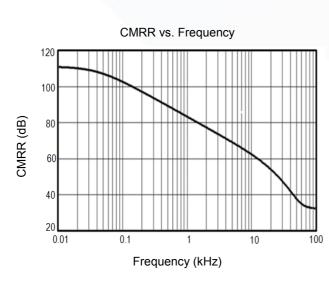




Time (2µs/div)

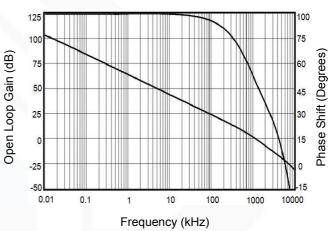


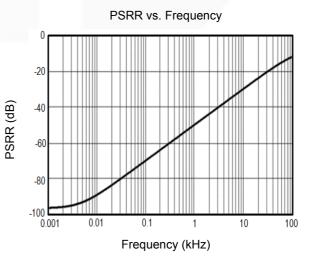




Supply Current vs. Temperature 50.0 47.5 Supply Current (µA) 45.0 42.5 40.0 37.5 35.0 32.5 -50.0 -15.0 20.0 55.0 90.0 125.0 Temperature (℃)

Open Loop Gain, Phase Shift vs. Frequency at +5V







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Application Note

Size

BDM321 series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the BDM321 packages save space on printed circuit boards and enable the design of smaller electronic products.

Power Supply Bypassing and Board Layout

BDM321 series operates from a single 2.1V to 5.5V supply or dual $\pm 1.05V$ to $\pm 2.75V$ supplies. For best performance, a 0.1μ F ceramic capacitor should be placed close to the V_{DD} pin in single supply operation. For dual supply operation, both V_{DD} and V_{SS} supplies should be bypassed to ground with separate

0.1uF ceramic capacitors

Low Supply Current

The low supply current (typical 40µA per channel) of BDM321 will help to maximize battery life. They are ideal for battery powered systems.

Operating Voltage

BDM321 operates under wide input supply voltage (2.1V to 5.5V). In addition, all temperature specifications apply from -40 $^{\circ}$ C to +125 $^{\circ}$ C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime.

Rail-to-Rail Input

The input common-mode range of BDM321 extends 100mV beyond the supply rails (V_{SS} -0.1V to V_{DD} +0.1V). This is achieved by using complementary input stage. For normal operation, inputs should be limited to this range.

Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of BDM321 can typically swing to less than 5mV from supply rail in light resistive loads (>100k Ω), and 30mV of supply rail in moderate resistive loads (10k Ω).

Capacitive Load Tolerance

The BDM321 is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create

apole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

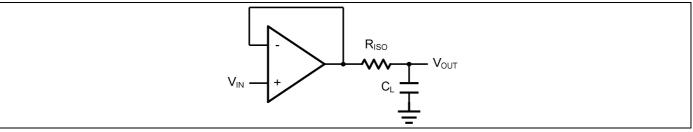


Figure 2. Indirectly Driving a Capacitive Load Using Isolation Resistor



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BDM321

The bigger the R_{ISO} resistor value, the more stable V_{OUT} will be. However, if there is a resistive load R_L in parallel with the capacitive load, a voltage divider (proportional to R_{ISO}/R_L) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. R_F provides the DC accuracy by feed-forward the V_{IN} to R_L. C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of C_F. This in turn will slow down the pulse response.

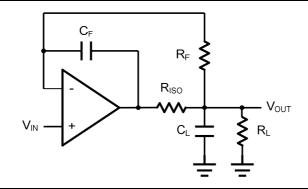


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy



Typical Application Circuits

Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using BDM321.

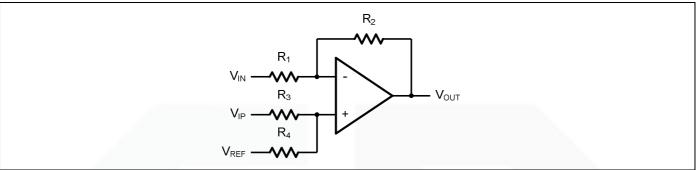


Figure 4. Differential Amplifier

$$V_{\text{OUT}} = \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_4}{R_1} V_{\text{IN}} - \frac{R_2}{R_1} V_{\text{IP}} + \left(\frac{R_1 + R_2}{R_3 + R_4}\right) \frac{R_3}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e. $R_1=R_3$ and $R_2=R_4$), then

$$V_{\rm OUT} = \frac{R_2}{R_1} (V_{\rm IP} - V_{\rm IN}) + V_{\rm REF}$$

Low Pass Active Filter

The low pass active filter is shown in Figure 5. The DC gain is defined by $-R_2/R_1$. The filter has a -20dB/decade roll-off after its corner frequency $f_C=1/(2\pi R_3 C_1)$.

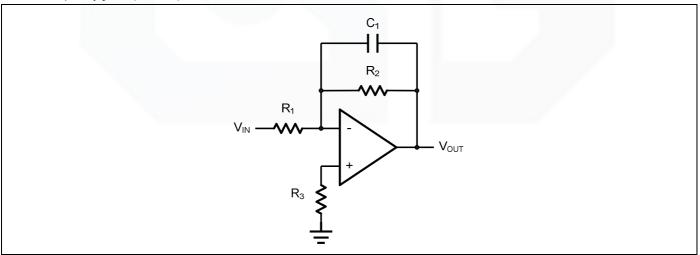


Figure 5. Low Pass Active Filter



Instrumentation Amplifier

The triple BDM321 can be used to build a three-op-amp instrumentation amplifier as shown in Figure 6. The amplifier in Figure 6 is a high input impedance differential amplifier with gain of R2/R1. The two differential voltage followers assure the high input impedance of the amplifier.

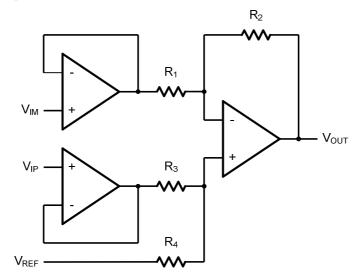
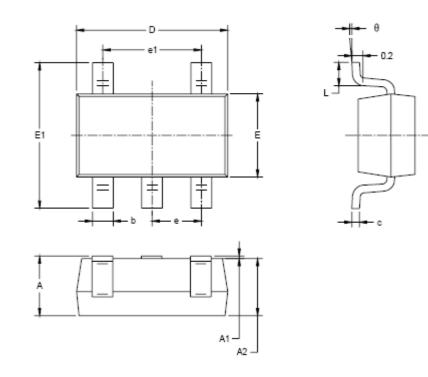


Figure 6. Instrument Amplifier



Package Information

SOT23-5



Dimensions In Inches			
X			
49			
04			
45			
20			
08			
19			
67			
16			
0.037 BSC			
0.075 BSC			
24			
•			
)			